

Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters



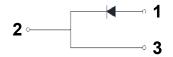


Part Number	Package	Qty(PCS)	
HIDH15S120A	TO-220C-2L	50	

Maximum Ratings (T_c=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	$V_{_{ m RRM}}$	1200	V			
DC Blocking Voltage	V_{DC}	1200	V			
		43.5		T _J = 25 °C		
Continuous Forward Current	I _F	21		T _J = 135 °C	Fig. 3	
		15		T _J = 152.5 °C		
Repetitive Peak		68		T _C = 25 °C, t _p = 10 ms, Half Sine Wave		
Forward Surge Current	I _{FRM}	44	Α	T_C = 110 °C, t_p = 10 ms, Half Sine Wave		
Non-Repetitive		100		T _C = 25 °C, t _p = 10 ms, Half Sine Wave		
Forward Surge	I _{FSM}	85		T _C = 110 °C,t _p = 10 ms, Half Sine Wave	Fig. 8	
Current Non-Repetitive Peak		900		$T_{\rm C}$ = 25 °C, $t_{\rm D}$ = 10 μ s, Pulse		
Forward Surge	F,Max	750		T _C = 110°C, t _p = 10 μs, Pulse		
Current		214		T _J = 25 °C		
Power Dissipation	P _{tot}	93	W	T _J = 110 °C	Fig. 4	
	ʃi²t	50	A ² s	$T_{c} = 25 ^{\circ}\text{C}, t_{p} = 10 \text{ms}$		
i²t Value		36		$T_{c} = 110^{\circ}\text{C}, t_{p} = 10 \text{ ms}$		





Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes	
- 177.8		1.6	1.8		I _F = 15 A, T _i = 25 °C		
Forward Voltage	V _F	2.2	3	V	I _F = 15 A, T _i = 175 °C	Fig. 1	
		35	200		V _R = 1200 V, T _i = 25 °C	F: 0	
Reverse Current	l _R	120	300	μΑ	V _R = 1200 V, T _i = 175 °C	Fig. 2	
Total Capacitive Charge	Q_c	77.5		nC	V _R = 800 V, T _i = 25 °C	Fig. 5	
		1200			$V_R = 0 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$		
Total Capacitance	С	70		pF	$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6	
		50			$V_R = 800 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$		
Capacitance Stored Energy	E _c	22		μJ	V _R = 800 V	Fig. 7	

Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

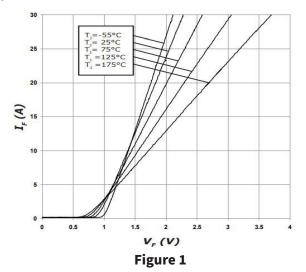
Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R _{e, JC (TYP)}	0.7	°C/W	
Junction Temperature	T _j	-55 to +175	°C	
Case & Storage Temperature	T _c	-55 to +175		
		1	Nm	M3 Screw
TO-220-2L Mounfting Torque	-	8.8	lbf-in	6-32 Screw

Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Notes
Human Body Model	НВМ	Class 3B (≥ 8000 V)
Charge Device Model	CDM	Class C3 (≥ 1000 V)



Typical Performance



Forward Characteristics

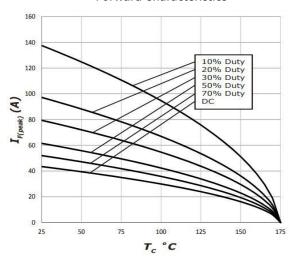
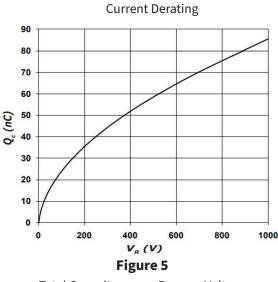


Figure 3



Total Capacitance vs. Reverse Voltage

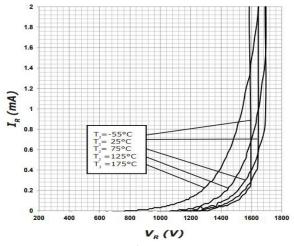


Figure 2

Reverse Characteristics

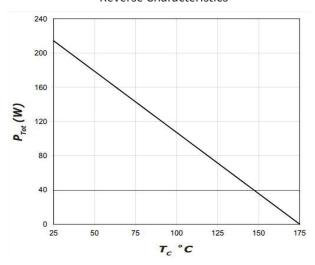


Figure 4

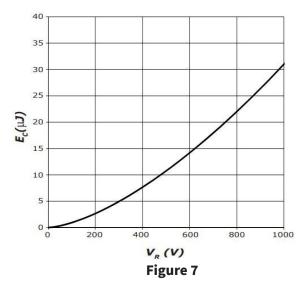
Power Derating

1400
1200
1000
800
400
400
0.1
1
1
10
100
1000
V_R (V)
Figure 6

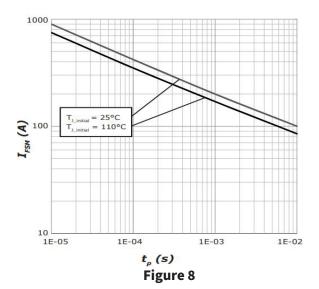
Capacitace vs. Reverse Voltage



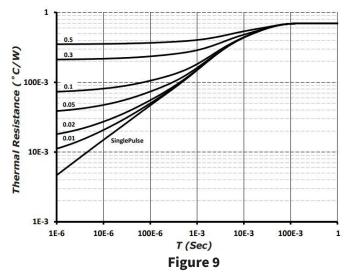
Typical Performance



Capacitance Stored Energy



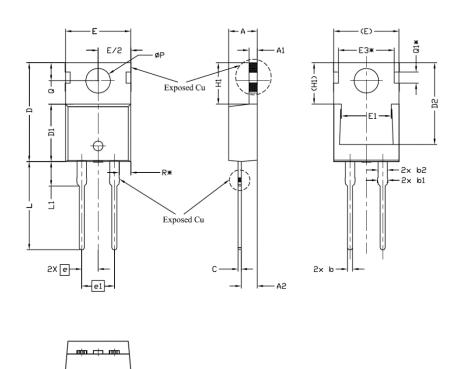
Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)



Transient Thermal Impedance

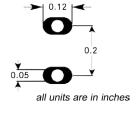


Package Information TO-220C-2L



CVMDOL		NOTES		
SYMBOL	MIN.	NOM.	MAX.	NOTES
Α	4,24	4.44	4,64	
A1	1.15	1.27	1.40	
A2	2.30	2.48	2.70	
ь	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1.20	1.45	1.70	
С	0.40	0.50	0.60	
D	14.70	15.37	16.00	4
D1	8.82	8.92	9.02	
D2	12.43	12.73	12.83	5
E	9.96	10.16	10.36	4,5
E1	6,86	7,77	8,89	5
E3*				
e				
e1	5.08BSC			
H1	6.30	6.45	6.60	5,6
٦	13.47	13.72	13,97	
L1	3.60	3.80	4.00	
ØP	3.75	3.84	3,93	
Q	2,60	2,80	3,00	
Q1*	1.73REF.			
R*				

Recommended Solder Pad Layout



TO-220C-2L

Attention

- Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.
- HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.
- Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc.

 When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.